FCC ID : 2APXNLACA092

1.1.Measuring Standard

FCC CFR 47 Part 1(1.1310) KDB 680106 D01 v03

1.2.Requirements

The EUT does comply with item 5(b) of KDB 680106 D01 v03

- 1) Power transfer frequency is less than 1MHz
- 2) Output power from each primary coil is less than or equal to 15 watts.
- 3) The transfer system includes only single primary and secondary coils. This includes charging systems that may have multiple primary coils and clients that able to detect and allow coupling only between individual pair of coils.
- 4) Client device is inserted in or placed directly in contact with the transmitter.
- 5) Mobile exposure conditions only (portable exposure conditions are not covered by this exclusion)
- 6) The aggregate H-field strengths at 15 cm surrounding the device and 20 cm above the top surface from all simultaneous transmitting coils are demonstrated to be less than 50% of the MPE limit.

1.3.Test Configuration

- The field strength of both H-field was measured at 15cm using the equipment list above for determining compliance with the MPE requirements of FCC Part 1.1310.
- 2) The RF power density was measured at Under maximum load test
- 3) Maximum H-field measurements were made 15cm from each side of the EUT. Along the side of the EUT and still 15cm away from the edge of the EUT, the field probes were positioned at the location where there is maximum field strength. The maximum H-field is reported below.
- This device uses a wireless charging circuit for power transfer operating at the frequency of 110 −148kHz. Thus, the 300kHz limits were used: H-field limit = 1.63 (A/m).

1.4.Test Procedure

- 1) The RF exposure test was performed in anechoic chamber.
- 2) The aggregate H-field strengths at 15 cm surrounding the device and 20 cm above the top surface
- 3) The highest emission level was recorded and compared with limit as soon as measurement of each points (A, B, C, D, E) were completed.
- 4) The EUT was measured according to the dictates of KDB 680106 D01 v03.

Remark:

The EUT's test position A, B, C, D, and E is valid for the H field measurements.

1.5.Test Setup



1.6.Limits

Frequency range (MHz)	Electric field strength (V/m)	Magnetic field strength (A/m)	Power density (mW/cm ²)	Averaging time (minutes)						
	(A) Limits for Occupational/Controlled Exposure									
0.3-3.0	614	1.63	*100	6						
3.0-30	1842/1	4.89/1	*900/f ²	6						
30-300	61.4	0.163	1.0	6						
300-1,500			f/300	6						
1,500-100,000			5	6						
	(B) Limits for Gener	ral Population/Uncontrolled	Exposure							
0.3-1.34	614	1.63	*100	30						
1.34-30	824/1	2.19/1	*180/f ²	30						
30-300	27.5	0.073	0.2	30						
300-1,500			f/1500	30						
1,500-100,000			1.0	30						

f = frequency in MHz * = Plane-wave equivalent power density

Remark: Emissions between 100 kHz to 300 kHz should be assessed versus the limits at 300 kHz in Table 1 of Section 1.1310: 1.63 A/m

1.7. Measuring Device and Test Equipment

For MPE Measurement

Item	Equipment	Manufacturer	Model No.	Serial No.	Last Cal.	Cal.
						Interval
1.	H-Field Probe	HIOKI	3471	110719810	Dec. 14, 2018	1 Year
	100 cm ² SENSOR					
2.	MAGNETIC FIELD	HIOKI	3470	110719810	Dec. 14, 2018	1 Year
	HiTESTER					

1.8.Description of Test Facility

Test Items	:	H field measurements	
Test Laboratory	:	Shenzhen Academy of Metrology and Quality Inspection	
Site Location	:	Bldg. of Metrology & Quality Inspection, Longzhu Road Nanshan	
		District, Shenzhen, Guangdong, China	

1.9.Measuring Results

EUT Test	Mea	sured H-Fi	50%	Limit				
Mode		1				Limit	(A/m)	
	Test	Test	Test	Test	Test	(Λ/m)	()	
	Position	Position	Position	Position	Position	(A/III)		
	А	В	С	D	Е			
1% Battery	0.470	0.468	0.475	0.469	0.462	0.815	1.63	
Level								
50% Battery	0.468	0.466	0.468	0.467	0.456	0.815	1.63	
Level								
99% Battery	0.464	0.462	0.461	0.466	0.460	0.815	1.63	
Level								

Table: H-Field Strength at 15 cm from the edges surrounding the EUT and 20cm from the top surface of the EUT

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1.10.Measuring Standard

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1.11.Requirements

The maximum operating frequency of the device is 205 kHz Thus, the minimum limit for Canada is 0.73 / f = 0.73 / 0.205 = 3.56 A/m > 0.258 A/m = PASS

1.12.Test Procedure

- 5) The RF exposure test was performed in anechoic chamber.
- 6) The aggregate H-field strengths at 10 cm surrounding the device and 10 cm above the top surface
- 7) The highest emission level was recorded and compared with limit as soon as measurement of each points (A, B, C, D, E) were completed.

Remark:

The EUT's test position A, B, C, D, and E is valid for the H field measurements.

1.13.Test Setup



1.14.Limits

Frequency Range (MHz)	Electric Field (V/m rms)	Magnetic Field (A/m rms)	Power Density (W/m ²)	Reference Period (minutes)			
0.003-10 ²¹	83	90	-	Instantaneous*			
0.1-10	-	0.73/ f	-	6**			
1.1-10	87/ f ^{0.5}	-	-	6**			
10-20	27.46	0.0728	2	6			
20-48	58.07/ f ^{0.25}	0.1540/ f ^{0.25}	8.944/ f ^{0.5}	6			
48-300	22.06	0.05852	1.291	6			
300-6000	$3.142 f^{0.3417}$	$0.008335 f^{0.3417}$	0.02619 <i>f</i> ^{0.6834}	6			
6000-15000	61.4	0.163	10	6			
15000-150000	61.4	0.163	10	616000/ f ^{1.2}			
150000-300000	$0.158 f^{0.5}$	$4.21 \ge 10^{-4} f^{0.5}$	6.67 x 10 ⁻⁵ f	616000/ f ^{1.2}			
Note: f is frequency in MHz. *Based on nerve stimulation (NS). ** Based on specific absorption rate (SAR).							

Table 4: RF Field Strength Limits for Devices Used by the General Public (Uncontrolled Environment)

Table 6: RF Field Strength Limits for Controlled Use Devices (Controlled Environment)

Frequency Range	Electric Field	Magnetic Field	Power Density	Reference Period				
(MHz)	(V/m rms)	(A/m rms)	(W/m ²)	(minutes)				
0.003-10 ²³	170	180	-	Instantaneous*				
0.1-10	-	1.6/ f	-	6**				
1.29-10	$193/f^{0.5}$	-	-	6**				
10-20	61.4	0.163	10	6				
20-48	129.8/ f ^{0.25}	0.3444/ f ^{0.25}	44.72/ f ^{0.5}	6				
48-100	49.33	0.1309	6.455	6				
100-6000	$15.60 f^{0.25}$	0.04138 f ^{0.25}	0.6455 <i>f</i> ^{0.5}	6				
6000-15000	137	0.364	50	6				
15000-150000	137	0.364	50	$616000/f^{1.2}$				
150000-300000	$0.354 f^{0.5}$	$9.40 \ge 10^{-4} f^{0.5}$	$3.33 \ge 10^{-4} f$	616000/ f ^{1.2}				
Note: f is frequency in MHz.								
*Based on nerve stimulation (NS).								
** Based on specific absorption rate (SAR).								

1.15.Measuring Device and Test Equipment

For MPE Measurement

Item	Equipment	Manufacturer	Model No.	Serial No.	Last Cal.	Cal.
						Interval
1.	H-Field Probe 100 cm ² SENSOR	HIOKI	3471	110719810	Dec. 14, 2018	1 Year
2.	MAGNETIC FIELD	HIOKI	3470	110719810	Dec. 14, 2018	1 Year
	HiTESTER					

1.16.Description of Test Facility

Test Items	:	H field measurements
Test Laboratory	:	Shenzhen Academy of Metrology and Quality Inspection
Site Location	:	Bldg. of Metrology & Quality Inspection, Longzhu Road
		Nanshan District, Shenzhen, Guangdong, China

1.17.Measuring Results

Table: H-Field Strength at 10 cm from the edges surrounding the EUT and 10cm from the top surface of the EUT

EUT Test	Measu	Measured H-Field Strength Values (A/m rms)TestTestTestTestTestTest					
Mode	Test						
	Position	Position	Position	Position	Position		
	А	В	С	D	Е		
1% Battery	0.477	0.470	0.499	0.472	0.482	3.56	
Level							
50% Battery	0.481	0.476	0.500	0.474	0.491	3.56	
Level							
99% Battery	0.486	0.487	0.510	0.490	0.489	3.56	
Level							

***** End of Test Report *****